

Yadong Xu

List of Publications by Year in descending order

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117
papers

2,440
citations

257450

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h-index

254184

43
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119
all docs

119
docs citations

119
times ranked

2101
citing authors

#	ARTICLE	IF	CITATIONS
1	Centimeter-Sized Inorganic Lead Halide Perovskite CsPbBr ₃ Crystals Grown by an Improved Solution Method. <i>Crystal Growth and Design</i> , 2017, 17, 6426-6431.	3.0	152
2	Exploring Lead-Free Hybrid Double Perovskite Crystals of (BA) ₂ CsAgBiBr ₇ with Large Mobility-Lifetime Product toward X-Ray Detection. <i>Angewandte Chemie - International Edition</i> , 2019, 58, 15757-15761.	13.8	151
3	High-sensitivity X-ray detectors based on solution-grown caesium lead bromide single crystals. <i>Journal of Materials Chemistry C</i> , 2020, 8, 1248-1256.	5.5	108
4	Ligand-Free, Quantum-Confined Cs ₂ Sn ₆ Perovskite Nanocrystals. <i>Chemistry of Materials</i> , 2017, 29, 7901-7907.	6.7	98
5	Enhanced X-ray Sensitivity of MAPbBr ₃ Detector by Tailoring the Interface-States Density. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 7522-7528.	8.0	96
6	Optical and electronic anisotropies in perovskitoid crystals of Cs ₃ Bi ₂ I ₉ studies of nuclear radiation detection. <i>Journal of Materials Chemistry A</i> , 2018, 6, 23388-23395.	10.3	91
7	Direct Radiation Detection by a Semiconductive Metal-Organic Framework. <i>Journal of the American Chemical Society</i> , 2019, 141, 8030-8034.	13.7	85
8	High-Performance X-ray Detection Based on One-Dimensional Inorganic Halide Perovskite CsPbI ₃ . <i>Journal of Physical Chemistry Letters</i> , 2020, 11, 432-437.	4.6	83
9	Ultrasensitive and Robust 120 keV Hard X-Ray Imaging Detector based on Mixed Halide Perovskite CsPbBr ₃ Single Crystals. <i>Advanced Materials</i> , 2022, 34, e2106562.	21.0	72
10	Zero-Dimensional Cs ₂ Tel ₆ Perovskite: Solution-Processed Thick Films with High X-ray Sensitivity. <i>ACS Photonics</i> , 2019, 6, 196-203.	6.6	70
11	Lead free halide perovskite Cs ₃ Bi ₂ I ₉ bulk crystals grown by a low temperature solution method. <i>CrystEngComm</i> , 2018, 20, 4935-4941.	2.6	60
12	Defect proliferation in CsPbBr ₃ crystal induced by ion migration. <i>Applied Physics Letters</i> , 2020, 116, .	3.3	60
13	Charge Transport Behavior in Solution-Grown Methylammonium Lead Tribromide Perovskite Single Crystal Using ± Particles. <i>Journal of Physical Chemistry C</i> , 2018, 122, 14355-14361.	3.1	56
14	High-Stability Flexible X-ray Detectors Based on Lead-Free Halide Perovskite Cs ₂ Tel ₆ Films. <i>ACS Applied Materials & Interfaces</i> , 2021, 13, 23928-23935.	8.0	45
15	Vertical Bridgman growth and characterization of CdMnTe crystals for gamma-ray radiation detector. <i>Journal of Crystal Growth</i> , 2011, 318, 1062-1066.	1.5	43
16	Solution-Grown Formamidinium Hybrid Perovskite (FAPbBr ₃) Single Crystals for ±-Particle and β-Ray Detection at Room Temperature. <i>ACS Applied Materials & Interfaces</i> , 2021, 13, 15383-15390.	8.0	41
17	Enhancing Carrier Transport Properties of Melt-grown CsPbBr ₃ Single Crystals by Eliminating Inclusions. <i>Crystal Growth and Design</i> , 2020, 20, 2424-2431.	3.0	35
18	Towards superior X-ray detection performance of two-dimensional halide perovskite crystals by adjusting the anisotropic transport behavior. <i>Journal of Materials Chemistry A</i> , 2021, 9, 13209-13219.	10.3	34

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19	Characterization of CdZnTe Crystals Grown Using a Seeded Modified Vertical Bridgman Method. IEEE Transactions on Nuclear Science, 2009, 56, 2808-2813.	2.0	31
20	Morphology of X-ray detector Cs ₂ Tel ₆ perovskite thick films grown by electrospray method. Journal of Materials Chemistry C, 2019, 7, 8712-8719.	5.5	29
21	Solution growth of In-doped CdMnTe crystals by the vertical Bridgman method with the ACRT technique. Journal of Crystal Growth, 2012, 355, 33-37.	1.5	27
22	SiO ₂ aerogel-embedded carbon foam composite with Co-Enhanced thermal insulation and mechanical properties. Ceramics International, 2019, 45, 23393-23398.	4.8	27
23	Melt-grown large-sized Cs ₂ Tel ₆ crystals for X-ray detection. CrystEngComm, 2020, 22, 5130-5136.	2.6	27
24	Matrix-controlled morphology evolution of Te inclusions in CdZnTe single crystal. Scripta Materialia, 2012, 67, 5-8.	5.2	26
25	Exploring Lead-Free Hybrid Double Perovskite Crystals of (BA) ₂ CsAgBiBr ₇ with Large Mobility Lifetime Product toward X-Ray Detection. Angewandte Chemie, 2019, 131, 15904-15908.	2.0	25
26	Low-Temperature Solution Growth and Characterization of Halogen (Cl, I)-Doped CsPbBr ₃ Crystals. Crystal Growth and Design, 2020, 20, 1638-1645.	3.0	25
27	Effects of sub-bandgap illumination on electrical properties and detector performances of CdZnTe:In. Applied Physics Letters, 2014, 104, .	3.3	24
28	Temperature dependence of photoluminescence properties of In-doped cadmium zinc telluride. Journal of Materials Research, 2008, 23, 1389-1392.	2.6	21
29	Study on temperature dependent resistivity of indium-doped cadmium zinc telluride. Journal Physics D: Applied Physics, 2009, 42, 035105.	2.8	21
30	Radiation damage on CdZnTe:In crystals under high dose 60Co γ -rays. CrystEngComm, 2013, 15, 10304.	2.6	21
31	Purely organic 4HCB single crystals exhibiting high hole mobility for direct detection of ultralow-dose X-radiation. Journal of Materials Chemistry A, 2020, 8, 5217-5226.	10.3	21
32	Study on the behaviors of impurities in cadmium zinc telluride. Journal of Crystal Growth, 2007, 304, 313-316.	1.5	20
33	Investigation of Te inclusion induced glides and the corresponding dislocations in CdZnTe crystal. CrystEngComm, 2012, 14, 417-420.	2.6	20
34	Anisotropic Performance of High-Quality MAPbBr ₃ Single-Crystal Wafers. ACS Applied Materials & Interfaces, 2020, 12, 51616-51627.	8.0	20
35	Influence of deep level defects on carrier lifetime in CdZnTe:In. Journal of Applied Physics, 2015, 117, .	2.5	19
36	Cu ₂ I ₂ Se ₆ : A Metal-Inorganic Framework Wide-Bandgap Semiconductor for Photon Detection at Room Temperature. Journal of the American Chemical Society, 2018, 140, 1894-1899.	13.7	19

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37	Enhanced Transmission from Visible to Terahertz in ZnTe Crystals with Scalable Subwavelength Structures. <i>ACS Applied Materials & Interfaces</i> , 2021, 13, 16997-17005.	8.0	19
38	Dislocation-mediated coupling mechanism between the microstructural defects and Te inclusions in CdZnTe single crystals. <i>Scripta Materialia</i> , 2014, 82, 17-20.	5.2	18
39	Effects of deep-level defects on carrier mobility in CdZnTe crystals. <i>Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment</i> , 2014, 767, 318-321.	1.6	17
40	Research into the electrical property variation of undoped CdTe and ZnTe crystals grown under Te-rich conditions. <i>Journal of Alloys and Compounds</i> , 2014, 612, 392-397.	5.5	17
41	Growth and Characterization of Detector-Grade Cd _{0.9} Zn _{0.1} Te Crystals by the Traveling Heater Method with the Accelerated Crucible Rotation Technique. <i>Journal of Electronic Materials</i> , 2018, 47, 1125-1130.	2.2	17
42	Optical and electrical properties of vanadium-doped ZnTe crystals grown by the temperature gradient solution method. <i>Optical Materials Express</i> , 2018, 8, 431.	3.0	17
43	Metal-Organic Frameworks-Based Fabry-Pérot Cavity Encapsulated TiO ₂ Nanoparticles for Selective Chemical Sensing. <i>Advanced Functional Materials</i> , 2022, 32, 2109541.	14.9	17
44	Migration of Te inclusions in CdZnTe single crystals under the temperature gradient annealing. <i>Journal of Crystal Growth</i> , 2014, 402, 15-21.	1.5	16
45	Stoichiometric Effects on the Photoelectric Properties of In ₂ Se ₃ Crystals for Neutron Detection. <i>Crystal Growth and Design</i> , 2018, 18, 2864-2870.	3.0	16
46	Effect of dimensional expansion on carrier transport behaviors of the hexagonal Bi-based perovskite crystals. <i>Journal of Energy Chemistry</i> , 2022, 66, 459-465.	12.9	16
47	Investigation on defect levels in CdZnTe:Al using thermally stimulated current spectroscopy. <i>Journal Physics D: Applied Physics</i> , 2010, 43, 345104.	2.8	15
48	Morphology evolution of micron-scale secondary phases in CdZnTe crystals grown by vertical Bridgman method. <i>Journal of Alloys and Compounds</i> , 2011, 509, 2338-2342.	5.5	15
49	Role of Stoichiometry in the Growth of Large Pb ₂ P ₂ Se ₆ Crystals for Nuclear Radiation Detection. <i>ACS Photonics</i> , 2018, 5, 566-573.	6.6	15
50	The preparation and characterization of quasi-one-dimensional lead based perovskite CsPbI ₃ crystals from HI aqueous solutions. <i>Journal of Crystal Growth</i> , 2018, 498, 1-4.	1.5	14
51	Precursor Engineering for Solution Method-Grown Spectroscopy-Grade CsPbBr ₃ Crystals with High Energy Resolution. <i>Chemistry of Materials</i> , 2022, 34, 3993-4000.	6.7	14
52	Indentation-introduced dislocation rosettes and their effects on the carrier transport properties of CdZnTe crystal. <i>CrystEngComm</i> , 2016, 18, 5667-5673.	2.6	13
53	Two-Dimensional Dion-Jacobson Perovskite (NH ₃ CH ₃ NH ₂) ₂ CsPb ₂ Br ₇ with High X-ray Sensitivity and Peak Discrimination of Î±-Particles. <i>Journal of Physical Chemistry Letters</i> , 2022, 13, 1187-1193.	4.6	13
54	Ion Migration Controlled Stability in Î±-Particle Response of CsPbBr _{2.4} Cl _{0.6} Detectors. <i>Journal of Physical Chemistry C</i> , 2021, 125, 4235-4242.	3.1	12

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55	Investigation of dislocation migration in substrate-grade CdZnTe crystals during post-annealing. Journal of Crystal Growth, 2017, 457, 343-348.	1.5	11
56	Secondary Phase Particles in Cesium Lead Bromide Perovskite Crystals: An Insight into the Formation of Matrix-Controlled Inclusion. Journal of Physical Chemistry Letters, 2020, 11, 5625-5631.	4.6	11
57	Oriented preparation of Large-Area uniform Cs ₂ TeI ₆ perovskite film for high performance X-ray detector. Journal of Colloid and Interface Science, 2022, 624, 629-636.	9.4	11
58	Interplay mechanism between secondary phase particles and extended dislocations in CdZnTe crystals. CrystEngComm, 2015, 17, 8639-8644.	2.6	10
59	Effects of Te inclusions on charge-carrier transport properties in CdZnTe radiation detectors. Nuclear Instruments & Methods in Physics Research B, 2015, 343, 89-93.	1.4	10
60	Quality improvement of CdMnTe:In single crystals by an effective post-growth annealing. Journal of Crystal Growth, 2016, 451, 194-199.	1.5	10
61	Preparation of indium tin oxide contact to n-CdZnTe gamma-ray detector. Applied Physics Letters, 2018, 112, 112101.	3.3	10
62	Centimeter size BiSeI crystal grown by physical vapor transport method. Journal of Crystal Growth, 2019, 517, 7-11.	1.5	10
63	Terahertz emission from layered GaTe crystal due to surface lattice reorganization and in-plane noncubic mobility anisotropy. Photonics Research, 2019, 7, 518.	7.0	10
64	The study on Schottky contact between Au and clean CdZnTe. Surface Science, 2006, 600, 2629-2632.	1.9	9
65	Irradiation-Induced Defects in Cd _{0.9} Zn _{0.1} Te:Al. Journal of Electronic Materials, 2012, 41, 3044-3049.	2.2	9
66	Axial distribution of deep-level defects in as-grown CdZnTe:In ingots and their effects on the material's electrical properties. Journal of Crystal Growth, 2015, 409, 71-74.	1.5	9
67	An Effective Purification Process for the Nuclear Radiation Detector Tl ₆ SeI ₄ . Crystal Growth and Design, 2018, 18, 3484-3493.	3.0	9
68	Preparation, Structure Evolution, and Metal-Insulator Transition of Na _x RhO ₂ Crystals (0.25 ≤ x ≤ 1). Inorganic Chemistry, 2018, 57, 2730-2735.	4.0	9
69	Spin reorientation functionality in antiferromagnetic TmFe _{1-x} In _x O ₃ polycrystalline samples. Journal of Alloys and Compounds, 2019, 789, 80-89.	5.5	9
70	MAPbBr ₃ Crystals Improved by Accurate Solution-Grown Procedure for Alpha Particle Detection. Frontiers in Physics, 2020, 7, .	2.1	9
71	Narrow shape distribution of Te inclusions in ZnTe single crystals grown from Te solution. Journal of Crystal Growth, 2014, 404, 14-19.	1.5	8
72	Effects of Crystal Growth Methods on Deep-Level Defects and Electrical Properties of CdZnTe:In Crystals. Journal of Electronic Materials, 2015, 44, 518-523.	2.2	8

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73	Comparison of ZnTe bulk crystals grown by the temperature gradient solvent method using elemental and compound materials. <i>Optical Materials Express</i> , 2016, 6, 3309.	3.0	8
74	Study on twin boundaries and Te particles in CdMnTe crystals for nuclear detector application. <i>Journal of Crystal Growth</i> , 2013, 364, 128-132.	1.5	7
75	Controlling the Vapor Transport Crystal Growth of $\text{Hg}_{3}\text{Se}_{2}\text{I}_{2}$ Hard Radiation Detector Using Organic Polymer. <i>Crystal Growth and Design</i> , 2019, 19, 2074-2080.	3.0	7
76	Direct Detection of Fast Neutrons by Organic Semiconducting Single Crystal Detectors. <i>Advanced Functional Materials</i> , 2022, 32, 2108857.	14.9	7
77	Size and distribution of Te inclusions in detector-grade CdZnTe ingots. <i>Progress in Natural Science: Materials International</i> , 2011, 21, 66-72.	4.4	6
78	Correlated analysis of 2 MeV proton-induced radiation damage in CdZnTe crystals using photoluminescence and thermally stimulated current techniques. <i>Nuclear Instruments & Methods in Physics Research B</i> , 2016, 386, 16-21.	1.4	6
79	Te inclusion-induced electrical field perturbation in CdZnTe single crystals revealed by Kelvin probe force microscopy. <i>Micron</i> , 2016, 88, 48-53. Study on the local stress induced dislocations on $\langle \text{mml:math} \text{xmlns:mml="http://www.w3.org/1998/Math/MathML" altimg="si1.gif"} \rangle$	2.2	6
80			

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91	The analysis of X-ray response of CdZnTe detectors. Science China Technological Sciences, 2012, 55, 2295-2299.	4.0	4
92	One pillared-layer In_2Po framework with a rare tetracobalt-formate (4,4) sheet exhibiting a field-induced magnetic transition. Inorganic Chemistry Communication, 2014, 41, 58-61.	3.9	4
93	HRTEM study on the ordered phases in $\text{Hg}_3\text{In}_2\text{Te}_6$ crystals grown by Bridgman method. CrystEngComm, 2014, 16, 5073-5079.	2.6	4
94	Comparison of In doped and In, Pb co-doped $\text{Cd}_{0.9}\text{Zn}_{0.1}\text{Te}$. Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment, 2015, 790, 10-13.	1.6	4
95	Space-Charge Manipulation Under Sub-bandgap Illumination in Detector-Grade CdZnTe. Journal of Electronic Materials, 2015, 44, 3229-3235.	2.2	4
96	Enhanced terahertz response of diluted magnetic semiconductor $\text{Zn}_{1-x}\text{MnxTe}$ crystals. Optical Materials Express, 2018, 8, 157.	3.0	4
97	Purification and Improved Nuclear Radiation Detection of Tl_6Si_4 Semiconductor. Crystal Growth and Design, 2019, 19, 4738-4744.	3.0	4
98	Effect of Ga substitution for In in LiInSe_2 crystals on carrier transport behaviors and alpha particles detection. Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment, 2020, 949, 1627.	1.6	4
99	Self-trap-state-adjustable photoluminescence of quasi-one-dimensional RbPbI_3 and Cs substitutional counterparts. Journal of Materials Chemistry C, 2020, 8, 12108-12112.	5.5	4
100	Photoconductive gain under low-flux X-ray irradiation in 4HCB organic single crystal detectors. Applied Physics Express, 2020, 13, 071004.	2.4	4
101	Growth of bismuth- and antimony-based chalcogenide single crystals by the physical vapor transport method. CrystEngComm, 2022, 24, 1094-1099.	2.6	4
102	Study of Te nanoprecipitates in CdZnTe crystals. Journal of Materials Research, 2010, 25, 1298-1303.	2.6	3
103	Defects in CdMnTe crystals for nuclear detector applications. Journal of Semiconductors, 2013, 34, 043003.	3.7	3
104	Study on the bias-dependent effects of proton-induced damage in CdZnTe radiation detectors using ion beam induced charge microscopy. Micron, 2016, 88, 54-59.	2.2	3
105	Effects of Ga δ -Te interface layer on the potential barrier height of CdTe/GaAs heterointerface. Physical Chemistry Chemical Physics, 2016, 18, 2639-2645.	2.8	3
106	Controlled thermal shrinking of gold nanoparticle-decorated polystyrene substrate for advanced surface-enhanced Raman spectroscopy. Applied Surface Science, 2019, 466, 262-267.	6.1	3
107	Solution-grown Hypervalent CsI_3 Crystal for High-sensitive X-ray Detection. Physica Status Solidi (B): Basic Research, 2020, 257, 1900290.	1.5	3
108	TEM study on HgIn_2Te_4 precipitates in $\text{Hg}_3\text{In}_2\text{Te}_6$ crystals grown by the Bridgman method. CrystEngComm, 2014, 16, 7660-7666.	2.6	2

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109	Improvement of the THz response of Zn _{1-x} Mn _x Te bulk crystals grown by a temperature gradient solution method. <i>CrystEngComm</i> , 2017, 19, 3051-3057.	2.6	2
110	Resolving electronic inhomogeneity in CdZnTe bulk crystal via scanning microwave impedance microscopy. <i>Physica Status Solidi (B): Basic Research</i> , 2017, 254, 1600474.	1.5	2
111	Studies on Cr electrode of CdZnTe detector for high energy radiation detection. <i>Journal of Materials Science: Materials in Electronics</i> , 2018, 29, 5049-5056.	2.2	2
112	Enhanced ultrabroadband antireflection properties of ZnTe crystal with sub-wavelength surface structures by maskless reactive ion etching method. <i>Superlattices and Microstructures</i> , 2020, 137, 106353.	3.1	2
113	Correlation of fundamental photoreflectance spectra with surface quality of bulk ZnTe semiconductor grown from Te solution. <i>Crystal Research and Technology</i> , 2014, 49, 353-359.	1.3	1
114	The establishment and performance of IBIC microscopy at Fudan University. <i>Nuclear Instruments & Methods in Physics Research B</i> , 2019, 450, 122-126.	1.4	1
115	Solution-grown Hypervalent CsI ₃ Crystal for High-sensitive X-ray Detection. <i>Physica Status Solidi (B): Basic Research</i> , 2020, 257, 2070012.	1.5	1
116	Laser terahertz emission microscopy revealing the local fluctuation of terahertz generation induced by Te inclusion. <i>Applied Physics Letters</i> , 2021, 118, 131113.	3.3	0
117	Solar-blind UV detection by ultra-wide-bandgap 4HCB organic single crystal semiconductor. <i>Applied Physics Letters</i> , 2022, 120, 013301.	3.3	0